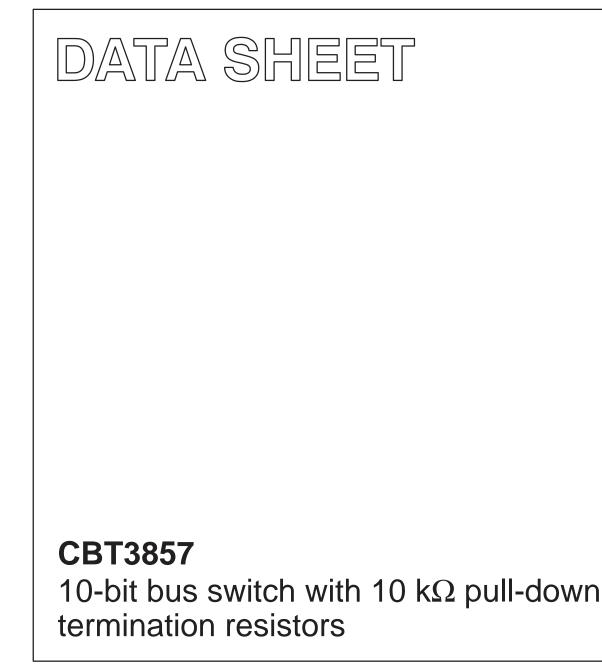
INTEGRATED CIRCUITS



Product specification Supersedes data of 1998 Dec 10 1999 Sep 14



Philips Semiconductors

CBT3857

FEATURES

- Enable signal is SSTL_2 compatible
- Optimized for use in Double Data Rate (DDR) SDRAM applications
- Flow-through architecture optimizes PCB layout
- Designed to be used with 200 Mbps
- Switch on resistance is designed to eliminate the need for series resistor to DDR SDRAM
- Internal 10 kΩ pull-down resistors on B port
- Internal 50 kΩ pull-up resistor on output enable input
- Full DDR solution provided when used with SSTL16857 and PCK857
- Latch-up protection exceeds 500 mA per JESD78
- ESD protection exceeds 2000 V HBM per JESD22-A114, 200 V MM per JESD22-A115 and 1000 V CDM per JESD22-C101

QUICK REFERENCE DATA

DESCRIPTION

This 10-bit bus switch is designed for 3 V to 3.6 V V_{CC} operation and SSTL_2 output enable (\overline{OE}) input levels.

When \overline{OE} is LOW, the 10-bit bus switch is on and port A is connected to port B. When \overline{OE} is HIGH, the switch is open, and a high-impedance state exists between the two ports.

The low on-state resistance of the switch allows connections to be made with minimal propagation delay.

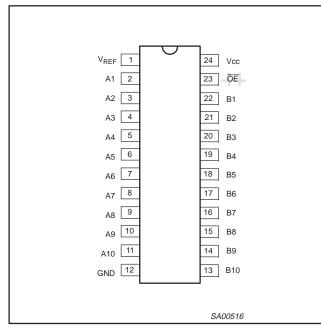
The CBT3857 is characterized for operation from 0° C to +85°C.

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C; GND = 0 V	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay An to Yn	C _L = 30 pF; V _{CC} = 3.3 V	720	ps
C _{IN}	Input capacitance	$V_I = 0 V \text{ or } V_{CC}$	2.8	pF
C _{OUT}	Output capacitance	Outputs disabled; $V_0 = 0 V \text{ or } V_{CC}$	6.4	pF
I _{CCZ}	Total supply current	V _{CC} = 3.6 V	1	mA

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	ORDER CODE	DWG NUMBER
24-Pin Plastic TSSOP Type I	0°C to +85°C	CBT3857 PW	SOT355-1

PIN CONFIGURATION



PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	V _{REF}	Reference output voltage
2, 3, 4, 5, 6, 7, 8, 9, 10, 11	A1–A10	Inputs
12	GND	Ground (V)
22, 21, 20, 19, 18, 17, 16, 15, 14, 13	B1–B10	Outputs
23	ŌĒ	Output enable
24	V _{CC}	Positive supply voltage

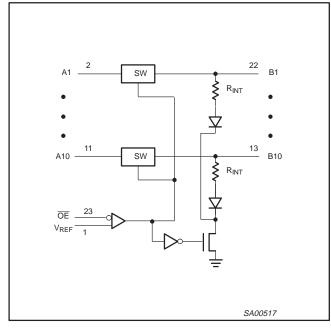
FUNCTION TABLE

INPUT OE	FUNCTION
L	A port = B port
н	Disconnect

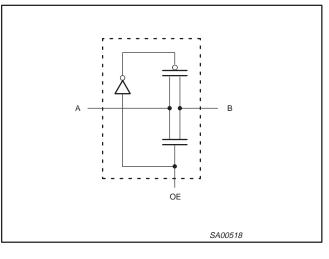
H = High voltage level

L = Low voltage level

LOGIC DIAGRAM (POSITIVE LOGIC)



SIMPLIFIED SCHEMATIC, EACH FET SWITCH



ABSOLUTE MAXIMUM RATINGS^{1, 3}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input clamp current	V _{I/O} < 0	-50	mA
VI	DC input voltage range (OE only) ²		V _{CC} + 0.5	V
T _{stg}	Storage temperature range		-65 to 150	°C
VI	DC input voltage range (except OE) ²		-0.5 to 4.6	V

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

3. The package thermal impedance is calculated in accordance with JESD 51.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	DADAMETED	•	LINUT		
	PARAMETER	Min	Тур	Max	UNIT
V _{CC}	DC supply voltage	3	3.3	3.6	V
V _{REF}	Reference voltage (0.38 x V _{CC})	1.15	1.25	1.35	V
V _{IH}	AC high-level input voltage	V _{REF} + 350 mV			V
VIL	AC low-level Input voltage			V _{REF} – 350 mV	V
V _{IH}	DC high-level input voltage	V _{REF} + 180 mV			V
V _{IL}	DC low-level Input voltage			V _{REF} – 180 mV	V
T _{amb}	Operating free-air temperature range	0		+85	°C

NOTE:

1. All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

Product specification

CBT3857

DC ELECTRICAL CHARACTERISTICS

	IBOL PARAMETER TEST CONDITIONS			LIMITS			
SYMBOL			T _{amb} = 0°C to +85°C			UNIT	
				Min	Typ ¹	Max	1
V _{IK}	Input clamp voltage	$V_{CC} = 3 \text{ V}; \text{ I}_{\text{I}} = -18 \text{ mA}$				-1.2	V
			ŌE		±0.73	±500	μΑ
			A Port		±0.1	±1	μΑ
łı	Input leakage current	$V_{CC} = 3.6 \text{ V}; \text{ V}_{I} = V_{CC} \text{ or GND}$	B Port		±20	±500	μΑ
			V _{REF}		±0.1	±1	μΑ
I _{CC}	Quiescent supply current	$V_{CC} = 3.6 \text{ V}; I_{O} = 0, V_{I} = V_{CC} \text{ or GND}$			0.7	1.5	mA
Cl	Control pins	$V_{I}=3 V \text{ or } 0$			2.8		pF
Ci _{O(OFF)}	Power-off leakage current	$V_0 = 3 V \text{ or } 0; \overline{OE} = V_{CC}$			6.4		pF
		V_{CC} = 3 V to 3.6 V; V_A = 0.8 V; V_B =	1.15 V	20	24	30	
r _{on} 2	On-resistance	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}; V_{A} = 1.7 \text{ V}; V_{B} = 1.35 \text{ V}$		20	24	30	Ω
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}; \text{ V}_{I} = 1.25 \text{ V}; \text{ I}_{I} = \pm 10 \text{ mA}$		20	24	30]
r _{off} 2	Off-resistance	$V_{CC} = 3 V \text{ to } 3.6 V; V_{I} = 1.65 V$		1			MΩ

NOTES:

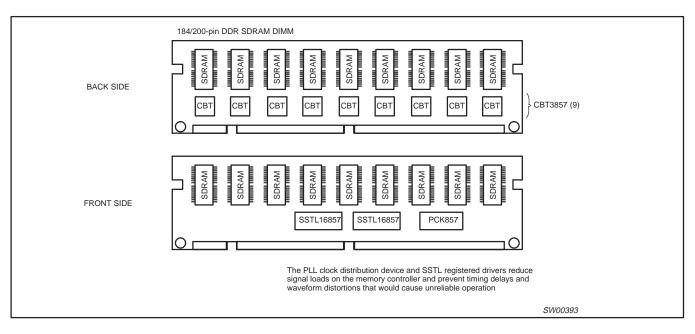
1. All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_{amb} = 25^{\circ}\text{C}$ 2. Measured by the voltage drop between the A and the B terminals at the indicated current through the switch. On–state resistance is determined by the lowest voltage of the two (A or B) terminals.

AC CHARACTERISTICS

SYMBOL	PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC} = +3.3 V ± 0.3 V		UNIT	
STMBOL			10 (001P01)	Min	Max	UNIT	
t _{pd}	Propagation delay ¹	A or B	B or A		750	ps	
t _{en}	enable	ŌĒ	A or B	1	3	ns	
t _{dis}	disable	ŌĒ	A or B	1	3	ns	

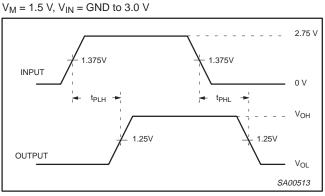
NOTE:

The propagation delay is based on the RC time constant of the typical on-state resistance of the switch and a load capacitance, when driven 1. by an ideal voltage source (zero output impedance); 24 $\Omega \times$ 30 pF.

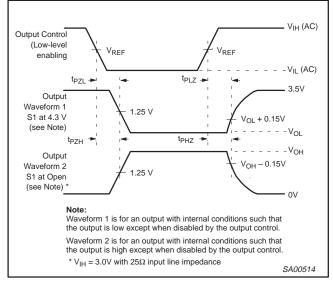


CBT3857

AC WAVEFORMS

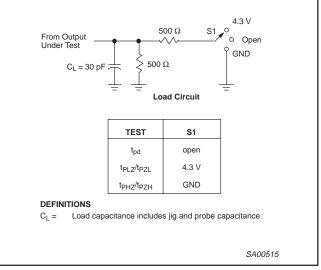


Waveform 1. Input (An) to Output (Yn) Propagation Delays



Waveform 2. 3-State Output Enable and Disable Times

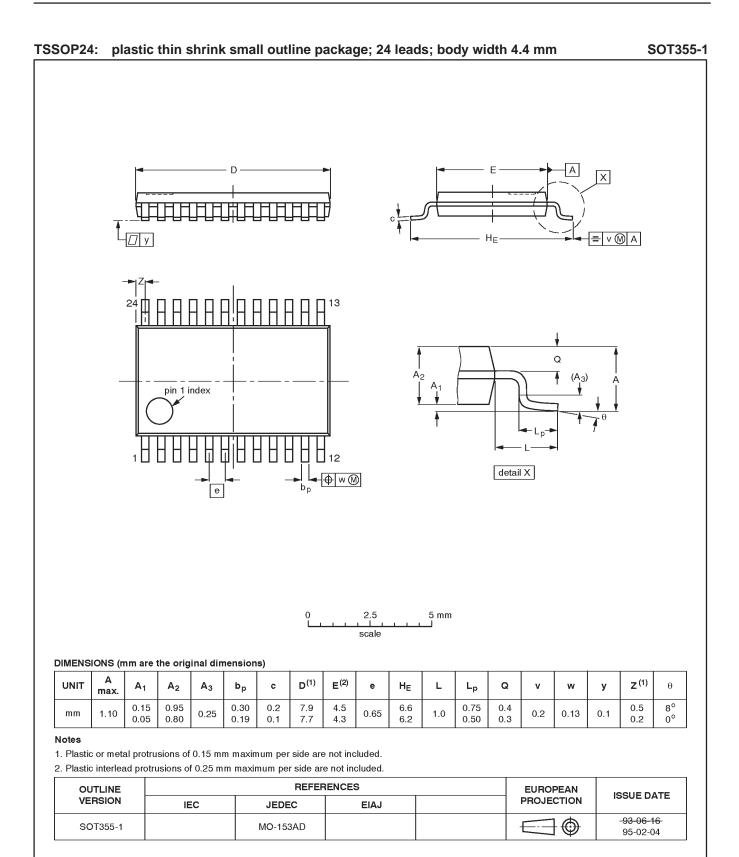
TEST CIRCUIT AND WAVEFORMS



NOTES:

- 1. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_f \leq 2.5 ns, t_f \leq 2.5 ns.
- 2. The outputs are measured one at a time with one transition per measurement.

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NOTES

CBT3857

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued datasheet before initiating or completing a design.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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